

RF (Radio Frequency) Type Low C and R

FEATURES

1. Low output capacitance between output terminals and low ON-resistance

2. High speed switching (Turn on time: typ. 200 $\mu s)$

3. High sensitivity

Control loads up to 250mA with input current 5mA

mm inch

4. Low-level off state leakage current The SSR has an off state leakage current

of several milliamperes, where as this PhotoMOS relay has only 20pA (typical) even with the rated load voltage

5. Controls low-level analog signals PhotoMOS relays features extremely lowclosed-circuit offset voltage to enable control of low-level analog signals without distortion

6. Low thermal electromotive force (Approx. 1 $\mu\text{V})$

PhotoMOS RELAYS

TYPICAL APPLICATIONS

Measuring and testing equipment

- Testing equipment for semiconductor performance IC tester, Liquid crystal driver tester,
- semiconductor performance tester 2. Board tester
- Bear board tester, In-circuit tester, function tester
- 3. Medical equipment Ultrasonic wave diagnostic machine
- 4. Multi-point recorder (warping, thermo couple)

TYPES

Туре	Output rating*			Part				
			Through hole terminal	S	urface-mount termir	Packing quantity		
	Load voltage	Load current			Tape and reel packing style		Tube	Tape and reel
			Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC type	40 V	150 mA	AQV221N	AQV221NA	AQV221NAX	AQV221NAZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.

*Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

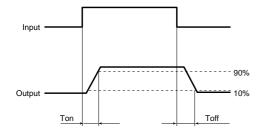
RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	Type of connec- tion	AQV221N(A)	Remarks	
	LED forward current	lF		50 mA		
Input	LED reverse voltage	VR		3 V		
	Peak forward current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW		
Output	Load voltage (peak AC)	VL		40 V		
		١L	A	0.15 A	A connection: Peak AC, DC B. C connection: DC	
	Continuous load current		В	0.18 A		
			С	0.25 A		
	Peak load current	Ipeak		0.45 A	A connection: 100 ms (1 shot), $V_L = DC$	
	Power dissipation	Pout		360 mW		
Total power dissipation		Ρτ		410 mW		
I/O isolation voltage		Viso		1,500 V AC		
Temperature limits	Operating	Topr		-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures	
	Storage	Tstg		-40°C to +100°C -40°F to +212°F		

Item					Type of connec- tion**	AQV221N(A)	Remarks
		Typical	- IFon		0.90 mA	l∟ = Max.	
Input	LED operate current				Maximum	3.0 mA	\square IL = IVIAX.
	LED turn off current		Minimum	Foff	_	0.4 mA	l∟ = Max.
			Typical	IFott		0.85 mA	
	LIED dropout voltage		Typical	VF		1.14 V (1.25 V at I⊧ = 50 mA)	I⊧ = 5 mA
			Maximum		_	1.5 V	
	On resistance #		Typical	- Ron	A	9.8 Ω	I⊧ = 0 mA I∟ = Max. Within 1 s on time
			Maximum			15 Ω	
			Typical	Ron	В	5 Ω	I⊧ = 5 mA
			Maximum			7.5 Ω	I∟ = Max. Within 1 s on time
Output			Typical	Ron	С	2.5 Ω	I⊧ = 5 mA I∟ = Max. Within 1 s on time
Output			Maximum			3.8 Ω	
	Output capacitance #		Typical	Cout	A	3.9 pF	$I_{F} = 0$ $V_{B} = 0V$ $f = 1 MHz$
			Maximum			5 pF	
	Utt state leakade current		Typical	- I _{Leak}	_	20 pA	IF = 0 VL = Max.
			Maximum			10 nA	
Transfer characteristics	Switching speed	Turn on time*	Typical	Ton	_	0.2 ms	IF = 5 mA IL = Max.
			Maximum			0.5 ms	
		Turn off time*	Typical	Toff	_	0.08 ms	I⊧ = 5 mA I∟ = Max.
			Maximum			0.2 ms	
	I/O canacitance		Typical	Ciso		0.8 pF	f = 1 MHz
			Maximum			1.5 pF	V _B = 0
	Initial I/O isolation resistance		Minimum	Riso	_	1,000 MΩ	500 V DC

Note: Recommendable LED forward current I⊧ = 5mA *Turn on/Turn off time



Other types of products than the C_{out} (typ. 3.9pF) and R_{on} (A connection typ. 9.8 ohm) combinations carried in this catalog are also available.

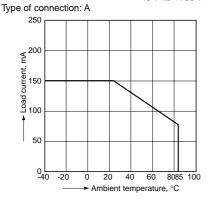
(There is a trade-off between R_{on} and C_{out} both cannot be reduced at the same time.) For more information, please contact our sales office in your area.

For Dimensions, see Page 440. For Schematic and Wiring Diagrams, see Page 444. For Cautions for Use, see Page 449.

REFERENCE DATA

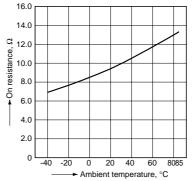
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: $-40^{\circ}C$ to $+85^{\circ}C$ $-40^{\circ}F$ to $+185^{\circ}F$



2. On resistance vs. ambient temperature characteristics

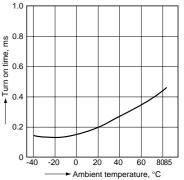
Measured portion: between terminals 4 and 6; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;

Load voltage: Max. (DC); Continuous load current: Max. (DC)

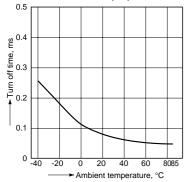


**For type of connection, see Page 444.

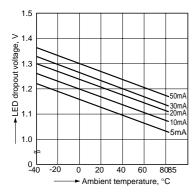
AQV221N

4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

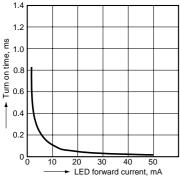


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



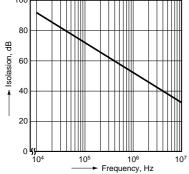
10. LED forward current vs. turn on time characteristics

Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



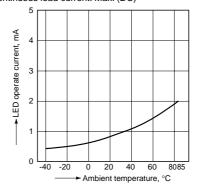
13. Isolation characteristics (50 Ω impedance)

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



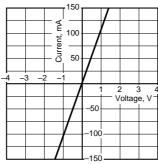
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)



8. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



11. LED forward current vs. turn off time char-

Load voltage: Max. (DC); Continuous load current:

Measured portion: between terminals 4 and 6;

Max. (DC); Ambient temperature: 25°C 77°F

acteristics

0.22

0.18

0.10

0.06

00

(50 Ω impedance)

뜅

Insertion loss.

2

0 **lss** 104

10 20 30 40 50

14. Insertion loss characteristics

Ambient temperature: 25°C 77°F

Measured portion: between terminals 4 and 6;

10⁵

10⁶

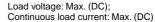
Frequency, Hz

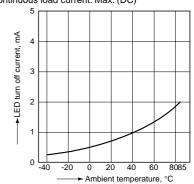
10

LED forward current, mA

ms

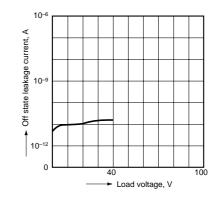
Turn off time, 0.14 6. LED turn off current vs. ambient temperature characteristics





9. Off state leakage current

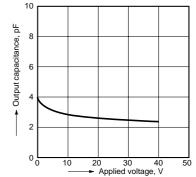
Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

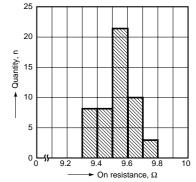
Measured portion: between terminals 4 and 6; Frequency: 1 MHz, 30 mVrms;

Ambient temperature: 25°C 77°F



15. On resistance distribution

Measured portion: between terminals 4 and 6 Continuous load current: 150mA(DC) Quantity, n=50; Ambient temperature: 25°C 77°F



100

AQV221N

